TOSHIBA Photocoupler Infrared LED + Photo IC

TLP550

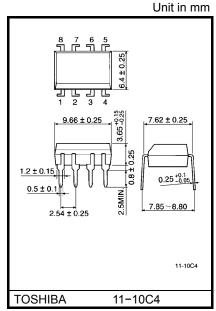
Digital Logic Isolation
Line Receiver Feedback Control
Power Supply Control
Switching Power Supply
Transistor Inverter

TLP550 constructs a high emitting diode and a one chip photo diodetransistor.

TLP550 has no base connection, and is suitable for application at noisy environmental condition.

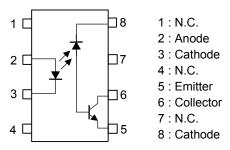
This unit is 8-lead DIP package.

- Isolation voltage: 2500 Vrms (min.)
- Switching speed: t_{pHL} , $t_{pLH} = 0.5\mu s$ (typ.)($R_L=1.9 \text{ k}\Omega$)
- TTL compatible
- UL recognized: UL1577, file No. E67349

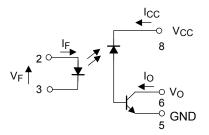


Weight: 0.54 g (typ.)

Pin Configuration (top view)



Schematic



Current Transfer Ratio

Classification		sfer Ratio (%) /IF)	Marking of Classification		
	MIN	MAX			
(None)	10	_	Blank, O, Y		
Rank O	19	_	0		
Rank Y	35	_	Υ		

Absolute Maximum Ratings (Ta = 25°C)

	Characteristic	Symbol	Rating	Unit	
	Forward current	(Note 1)	l _F	25	mA
LED	Pulse forward current	(Note 2)	I _{FP}	50	mA
	Peak transient forward current	(Note 3)	I _{FPT}	1	Α
	Reverse voltage		V_{R}	5	V
	Diode power dissipation	(Note 4)	P_{D}	45	mW
	Output current		ΙO	8	mA
Detector	Peak output current		I _{OP}	16	mA
	Supply voltage		V_{CC}	-0.5~15	V
	Output voltage		VO	-0.5~15	V
	Output power dissipation	(Note 5)	PO	100	mW
Оре	Operating temperature range		T _{opr}	-55~100	°C
Sto	Storage temperature range		T _{stg}	-55~125	°C
Lead solder temperature (10s)			T _{sol}	260	°C
Isolation voltage (AC, 1min., R.H. = 40~60%) (Note		(Note 6)	BVS	2500	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

2

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

(Note 1) Derate 0.8mA above 70°C.

(Note 2) 50% duty cycle, 1ms pulse width. Derate 1.6mA / °C above 70°C.

(Note 3) Pulse width 1µs, 300pps.

(Note 4) Derate 0.9mW / °C above 70°C.

(Note 5) Derate 2mW / $^{\circ}\text{C}$ above 70 $^{\circ}\text{C}.$

Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test condition		Min.	Тур.	Max.	Unit	
Forward voltage		V _F	I _F = 16 mA			1.45	1.65	1.85	V
LED	Forward voltage temperature coefficient	ΔV _F /ΔTa	I _F = 16 mA			_	-2	_	mV / °C
	Reverse current	I _R	V _R = 5 V			_	_	10	μΑ
	Capacitance between terminal	C _T	V _F = 0, f = 1MHz			_	60	-	pF
Detector	High level output current	I _{OH (1)}	I _F = 0 mA, V _{CC} = V _O = 5.5 V			-	3	500	nA
		I _{OH} (2)	I _F = 0 mA, V _{CC} = V _O = 15 V			_	_	5	μΑ
		Іон	I _F = 0 mA, V _{CC} = V _O = 15 V Ta = 70°C			_	_	50	μΑ
	High level supply voltage	Іссн	I _F = 0 mA, V _{CC} = 15 V		_	0.01	1	μΑ	
	Current transfer ratio	I _O / I _F	I _F = 16 mA V _{CC} = 4.5 V V _O = 0.4 V	Ta = 25°C		10	30	_	
Coupled					Rank: 0	19	30	_	%
					Rank : Y	35	50		
				Ta = 0~70°C		5	_	1	
					Rank: 0, Y	15	_	ı	
	Low level output voltage	V _{OL}	I_F = 16 mA, V_{CC} = 4.5 V I_O = 1.1 mA (rank 0: I_O = 2.4mA)				_	0.4	V
	Isolation resistance	R _S	R.H. = 40~60%, V = 1kV DC (Note 6)			-	10 ¹²	_	Ω
	Capacitance between input to output	CS	V = 0, f = 1MHz			_	0.8		pF

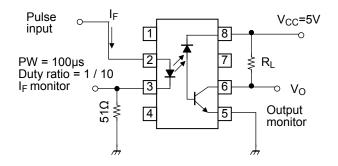
Switching Characteristics (Ta = 25°C)

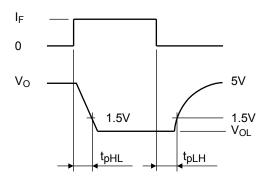
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Propagation delay time	t _{pHL}	$I_F = 0 \rightarrow 16$ mA, $V_{CC} = 5V$, $R_L = 4.1$ kΩ	_	0.3	0.8	μs
(H→ L)		(Note 7) Rank 0: R _L = 1.9 k	- Ω	0.5	0.8	
Propagation delay time	t _p LH	I_F = 16 \rightarrow 0 mA, V_{CC} = 5V, R_L = 4.1 kΩ	_	1.0	2.0	μs
$(L \rightarrow H)$		(Note 7) Rank 0: R _L = 1.9 k	- Ω	0.6	1.2	μδ
Common mode transient immunity at high output level		I_F = 0 mA, V_{CM} = 200 V_{p-p} R_L = 4.1 kΩ (rank 0: R_L = 1.9 kΩ) (Not	— e 8)	1500	_	V /µs
Common mode transient immunity at low output level	C _{ML}	I_F = 16 mA, V_{CM} = 200 V_{p-p} R_L = 4.1 kΩ (rank 0: R_L = 1.9 kΩ) (Note	— e 8)	-1500		V /µs

(Note 6) Device considered two-terminal device: Pins 1, 2, 3 and 4 shorted together and pin 5, 6, 7 and 8 shorted together.

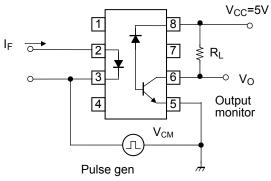
3

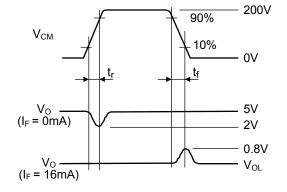
(Note 7) Switching time test circuit.





(Note 8) Common mode transient immunity test circuit.

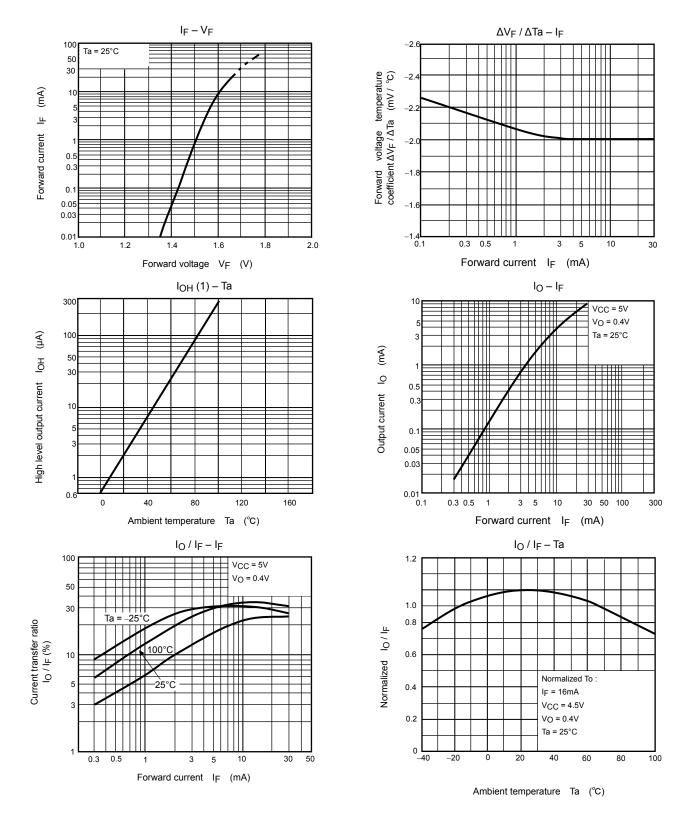


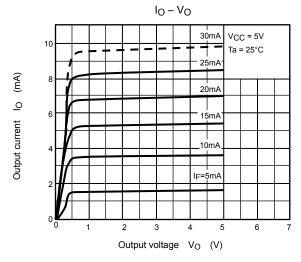


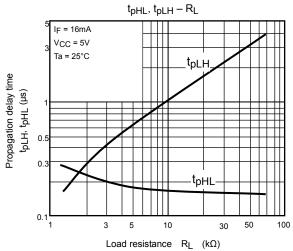
$$Z_{O}$$
=50 Ω

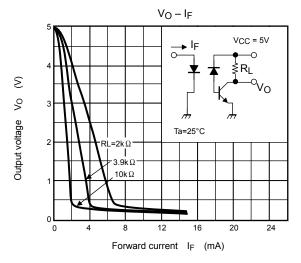
$$CM_{H} = \frac{160 \text{ (V)}}{t_{f} (\mu \text{s})} \quad CM_{L} = \frac{160 \text{ (V)}}{t_{f} (\mu \text{s})}$$

(Note 9) Maximum electrostatic discharge voltage for any pins: 100V (C = 200pF, R = 0)









6 2007-10-01

RESTRICTIONS ON PRODUCT USE

20070701-EN

- The information contained herein is subject to change without notice.
- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
 In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc.
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in his document shall be made at the customer's own risk.
- The products described in this document shall not be used or embedded to any downstream products of which manufacture, use and/or sale are prohibited under any applicable laws and regulations.
- The information contained herein is presented only as a guide for the applications of our products. No
 responsibility is assumed by TOSHIBA for any infringements of patents or other rights of the third parties which
 may result from its use. No license is granted by implication or otherwise under any patents or other rights of
 TOSHIBA or the third parties.
- GaAs(Gallium Arsenide) is used in this product. The dust or vapor is harmful to the human body. Do not break, cut, crush or dissolve chemically.
- Please contact your sales representative for product-by-product details in this document regarding RoHS
 compatibility. Please use these products in this document in compliance with all applicable laws and regulations
 that regulate the inclusion or use of controlled substances. Toshiba assumes no liability for damage or losses
 occurring as a result of noncompliance with applicable laws and regulations.